

# 1N5817, 1N5818, 1N5819

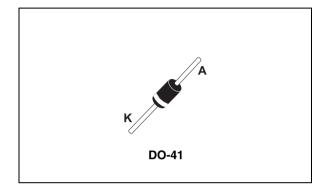
## Low drop power Schottky rectifier

## Features

- Very small conduction losses
- Negligible switching losses
- Extremely fast switching
- Low forward voltage drop
- Avalanche capability specified

## Description

Axial Power Schottky rectifier suited for Switch Mode Power Supplies and high frequency DC to DC converters. Packaged in DO-41 these devices are intended for use in low voltage, high frequency inverters, free wheeling, polarity protection and small battery chargers.



## Table 1. Device summary

Symbol	Value	Unit
I <sub>F(AV)</sub>	1	А
V <sub>RRM</sub>	40	V
Tj	150	°C
V <sub>F</sub> (max)	0.45	V

#### **Characteristics** 1

Table 2.	Absolute ratings	(limiting values)
Table 2.	Absolute ratings	(infiniting values)

ymbol	Para		Value			Unit
	Parameter		1N5817	1N5818	1N5819	Onit
/ <sub>RRM</sub>	Repetitive peak reverse	voltage	20	30	40	V
(RMS)	Forward rms current			10		
F(AV)	Average forward current $T_L = 125 \text{ °C}, \delta = 0.5$		1			A
I <sub>FSM</sub>	Surge non repetitive forward current $t_p = 10 \text{ ms Sinusoidal}$		25		A	
ARM	Repetitive peak avalanche power $t_p = 1 \ \mu s, T_j = 25 \ ^{\circ}C$		1200	1200	900	W
T <sub>stg</sub>	Storage temperature ra	-65 to + 150			°C	
Τj	Maximum operating junction temperature <sup>(1)</sup>		150		°C	
dV/dt	Critical rate of rise of reverse voltage		10000		V/µs	
I <sub>FSM</sub> P <sub>ARM</sub> T <sub>stg</sub> T <sub>j</sub>	current $T_L = 125 \ ^{\circ}C, \ \delta = 0.5$ Surge non repetitive forward current $t_p = 10 \ ms \ Sinusoidal$ Repetitive peak avalanche power $t_p = 1 \ \mu s, \ T_j = 25 \ ^{\circ}C$ Storage temperature rangeMaximum operating junction temperature <sup>(1)</sup>			1200 65 to + 150 150		900

1.  $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$  condition to avoid thermal runaway for a diode on its own heatsink.

#### Table 3. Thermal resistances

Symbol	Parameter	r	Value	Unit	
R <sub>th (j-a)</sub>	Junction to ambient	Lead length = 10 mm	100	°C/W	
R <sub>th (j-l)</sub>	Junction to lead	Lead length = 10 mm	45	°C/W	

#### Table 4. Static electrical characteristics

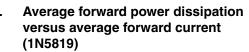
Symbol	Parameter	Tests conditions		1N5817	1N5818	1N5819	Unit
I <sub>B</sub> <sup>(1)</sup>	(1) Reverse leakage current	T <sub>j</sub> = 25 °C	V <sub>R</sub> = V <sub>RRM</sub>	0.5	0.5	0.5	mA
'R`´		$T_j = 100 \ ^\circ C$		10	10	10	mA
$V_{F}^{(1)}$	Forward voltage drop	T <sub>j</sub> = 25 °C	$I_F = 1 A$	0.45	0.50	0.55	V
		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 3 A	0.75	0.80	0.85	V

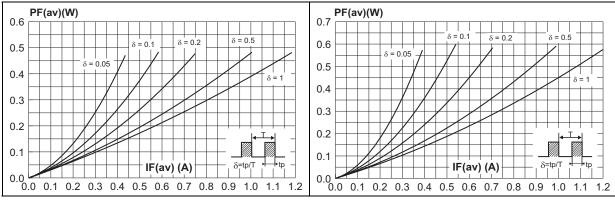
1. Pulse test :  $t_p$  = 380 µs,  $\delta$  < 2%

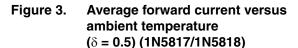
To evaluate the conduction losses use the following equations :  $P = 0.3 \times I_{F(AV)} + 0.090 \ I_{F}^{2} (\text{RMS})$  for 1N5817 / 1N5818  $P = 0.3 \times I_{F(AV)} + 0.150 \ I_{F}^{2} (\text{RMS})$  for 1N5819

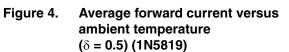


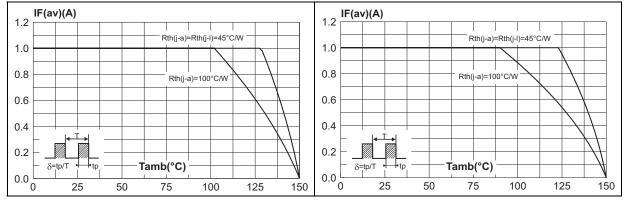
Figure 1. Average forward power dissipation Figure 2. versus average forward current (1N5817/1N5818)

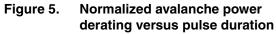






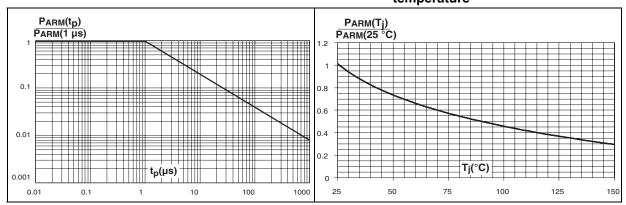






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Figure 6. Normalized avalanche power derating versus junction temperature



F=1MHz

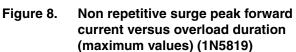
Tj=25°C

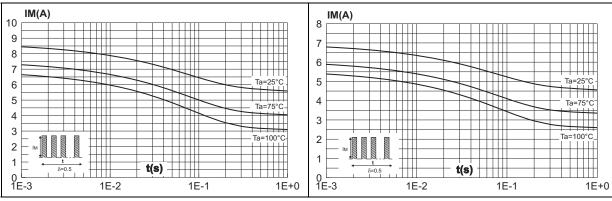
1N5818

40

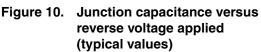
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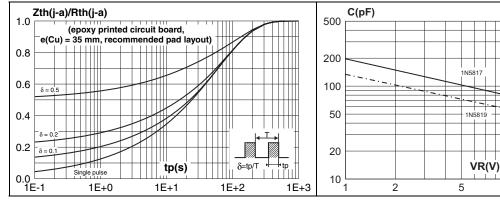
### Figure 7. Non repetitive surge peak forward current versus overload duration (maximum values) (1N5817/1N5818)





# Figure 9. Relative variation of thermal impedance junction to ambient versus pulse duration





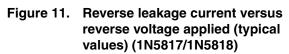
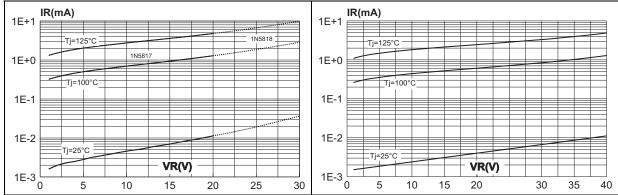


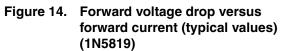
Figure 12. Reverse leakage current versus reverse voltage applied (typical values) (1N5819)

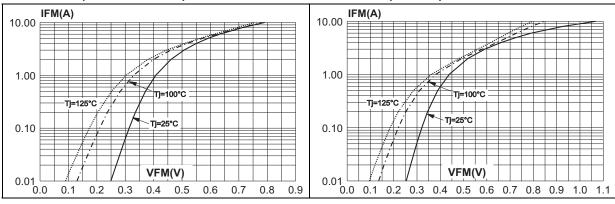
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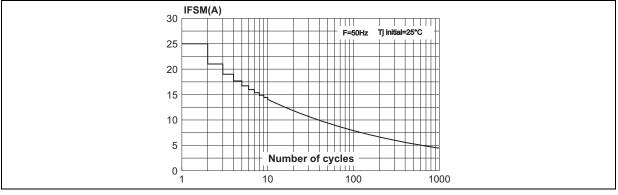


### Figure 13. Forward voltage drop versus forward current (typical values) (1N5817/1N5818)









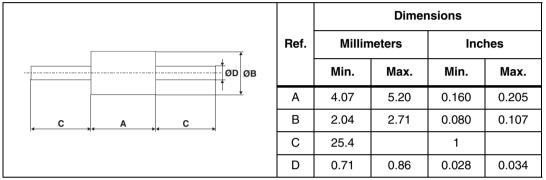


## 2 Package Information

- Epoxy meets UL94, V0
- Band indicates cathode

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK<sup>®</sup> is an ST trademark.

Table 5. DO-41 (Plastic) dimensions



## **3** Ordering information

Table 6.	Ordering information
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Order code	Marking	Package	Weight	Base qty	Delivery mode
1N581x	Part number cathode ring	DO-41	0.34 g	2000	Ammopack
1N581xRL	Part number cathode ring	DO-41	0.34 g	5000	Tape and reel

## 4 Revision history

Date	Revision	Changes	
Jul-2003	4A	Last update.	
04-Jul-2011	5	Updated Table 5.: DO-41 (Plastic) dimensions.	



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